# 2SC3836

# Silicon NPN Epitaxial

# **HITACHI**

ADE-208-1092 (Z) 1st. Edition Mar. 2001

### Application

Low frequency amplifier, switching

#### Outline

SPAK



- 1. Emitter
- 2. Collector
- 3. Base



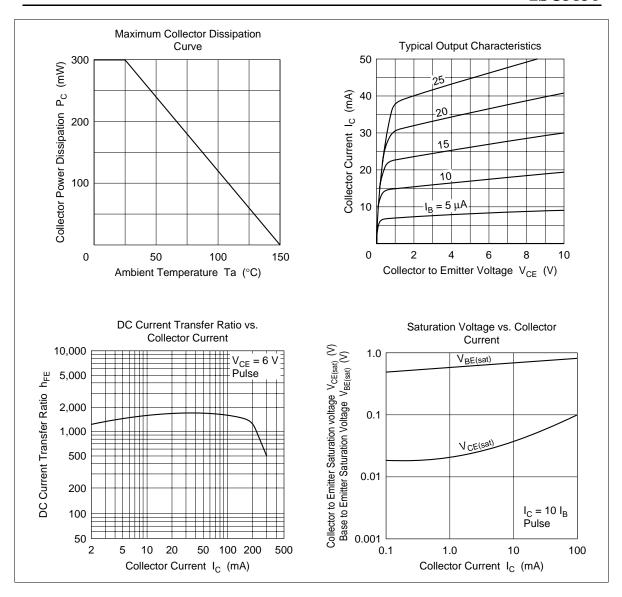
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### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

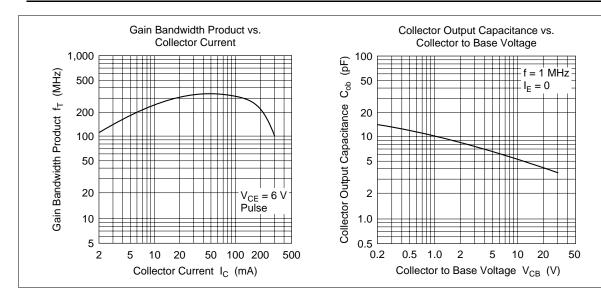
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	60	V
Collector to emitter voltage	V <sub>CEO</sub>	50	V
Emitter to base voltage	V <sub>EBO</sub>	15	V
Collector current	I <sub>c</sub>	300	mA
Collector power dissipation	P <sub>c</sub>	300	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

## Electrical Characteristics ( $Ta = 25^{\circ}C$ )

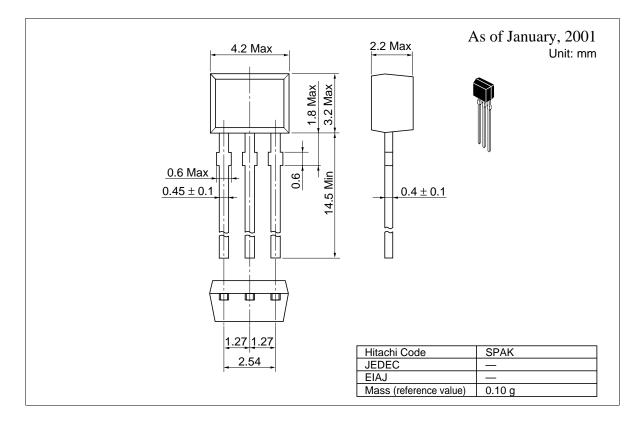
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	60	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{\text{(BR)CEO}}$	50	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{\text{(BE)EBO}}$	15	_	_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	1	μΑ	$V_{CB} = 50 \text{ V}, I_{E} = 0$
Base to emitter voltage	$V_{BE}$	_	_	0.75	V	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
DC current transfer ratio	h <sub>FE1</sub>	800	_	2000		$V_{CE} = 6 \text{ V}, I_{C} = 100 \text{ mA}$ (pulse test)
	h <sub>FE2</sub>	500	_	_		$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	0.3	V	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ (pulse test)



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#### **Package Dimensions**



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